

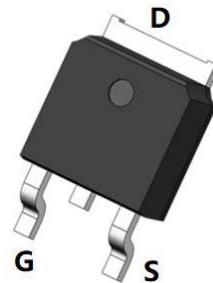
SSCV3NF500GT8

N-Channel Enhancement Mode Power MOSFET

➤ Features

V _{DS}	V _{GS}	R _{DS(ON)} Typ.	I _D
500V	±30V	2.5Ω@10V	1.5A

➤ Pin Configuration



TO252 (Top View)

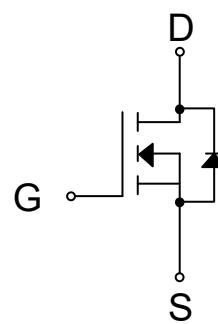
➤ Description

- This device is N-Channel enhancement MOSFET.
- Fast Switching.
- Improved dv/dt Capability.

100% UIS + ΔVDS + R_g Tested!

➤ Applications

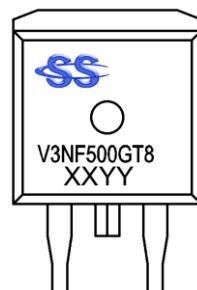
- Switch Mode Power Supply
- Uninterruptible Power Supply (UPS)
- Power Factor Correction(PFC)



Pin Configuration

➤ Ordering Information

Device	Package	Shipping
SSCV3NF500GT8	TO252	2500/Reel



Marking

(XXYY: Internal Traceability Code)

➤ **Absolute Maximum Ratings (T_J=25°C unless otherwise noted)**

Symbol	Parameter	Ratings	Unit
V _{DSS}	Drain-to-Source Voltage	500	V
V _{GSS}	Gate-to-Source Voltage	±30	V
I _D	Continuous Drain Current	T _J =25°C	3
		T _J =100°C	1.8
I _{DM}	Pulsed Drain Current ^a	12	A
E _{AS}	Single Pulsed Avalanche Energy	61	mJ
P _D	Power Dissipation, T _J =25°C	13.7	W
T _{STG} / T _J	Junction & Storage Temperature Range	-55 to 150	°C

➤ **Thermal Resistance Ratings (T_J=25°C unless otherwise noted)**

Symbol	Parameter	Ratings	Unit
R _{θJA}	Thermal Resistance, Junction to Ambient ^b	62	°C/W
R _{θJC}	Thermal Resistance, Junction to Case	9.1	

Note:

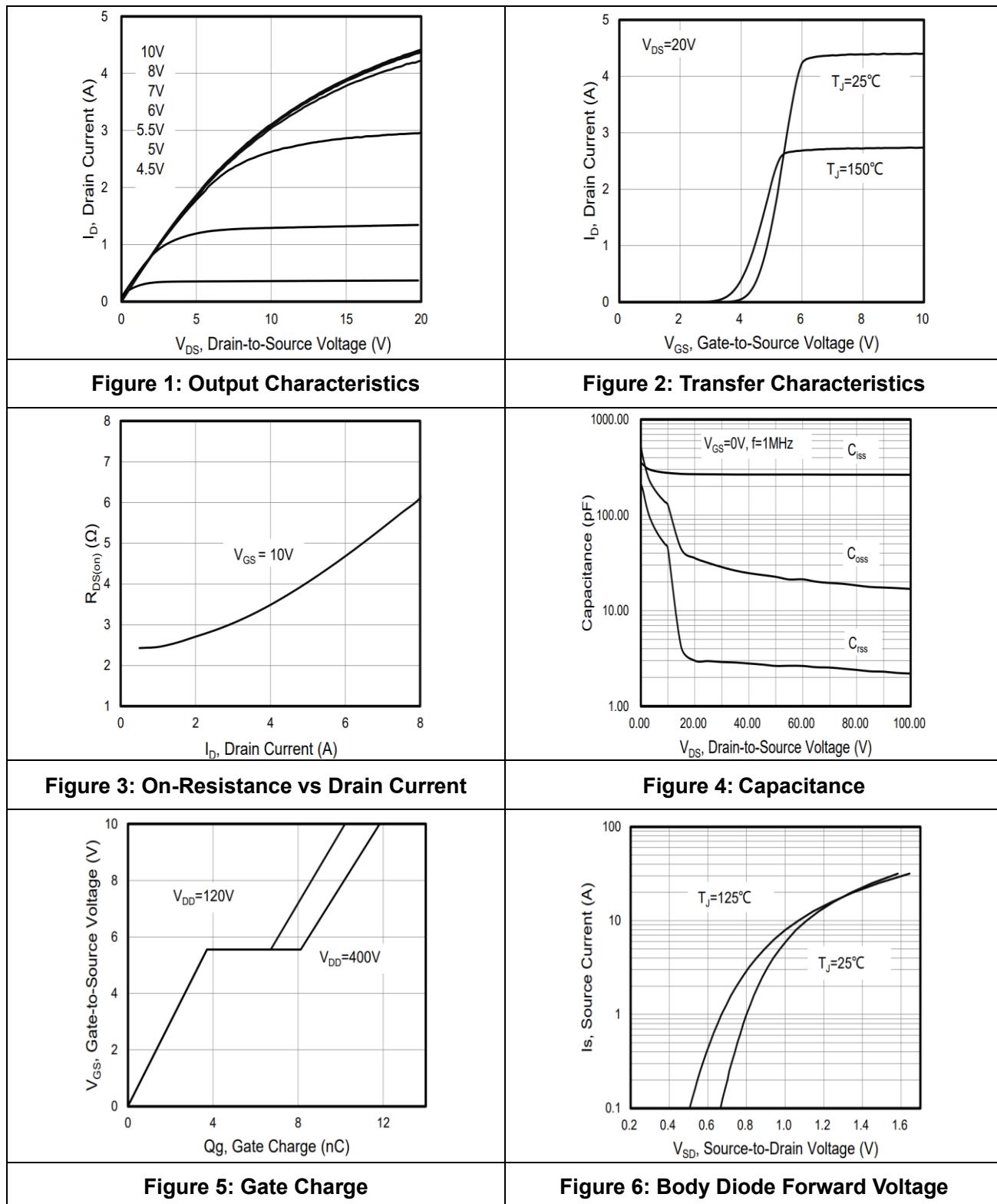
a. Repetitive Rating: Pulsed width limited by maximum junction temperature.

b. R_{θJA} is measured with the device mounted on a minimum recommended pad of 2oz copper FR4 PCB.

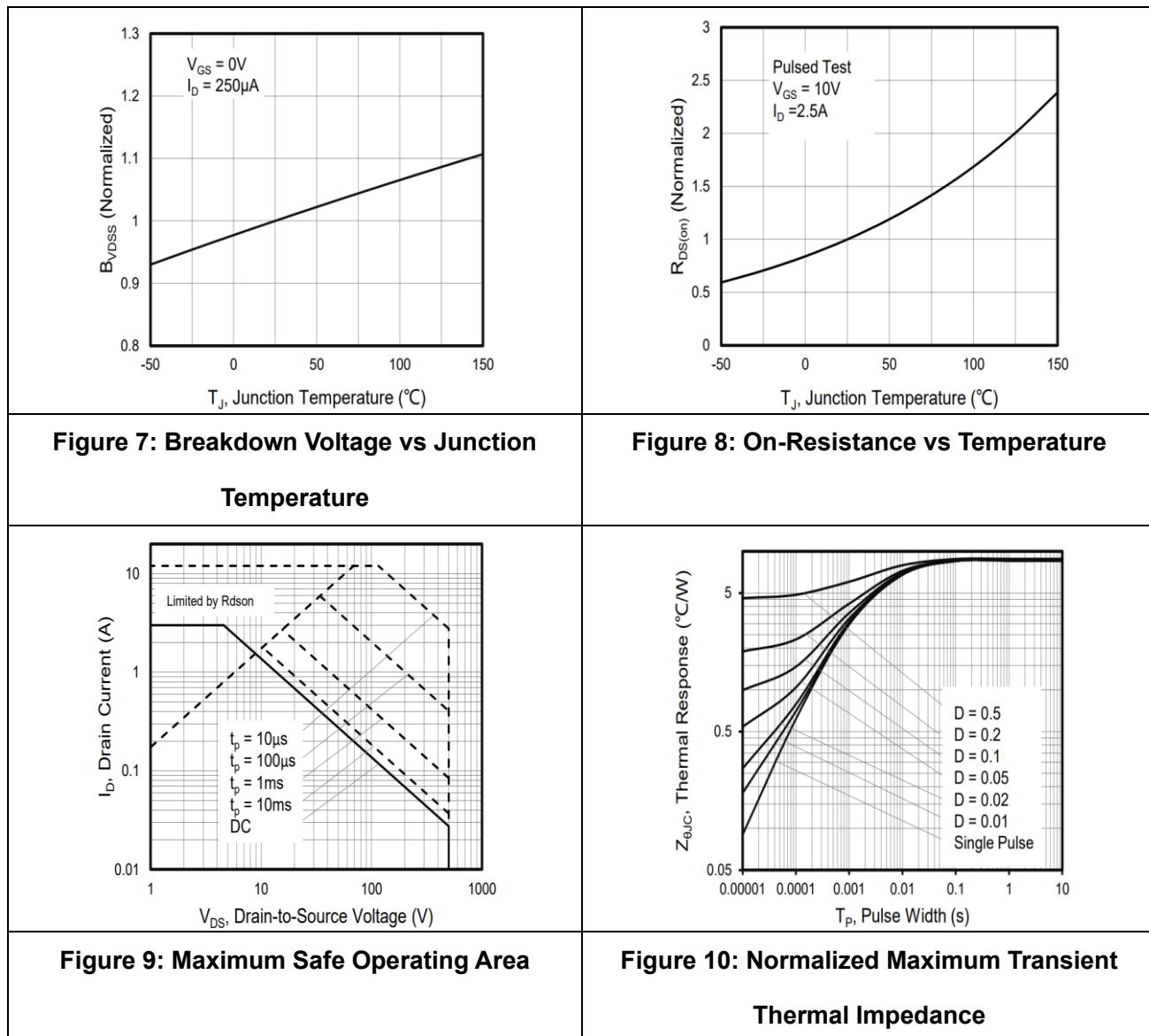
➤ Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250μA	500			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 500V, V _{GS} = 0V			1.0	μA
Gate-Source Leak Current	I _{GSS}	V _{GS} = ±30V, V _{DS} = 0V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250uA	2		4	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} = 10V, I _D = 1.5A		2.5	3	Ω
Input Capacitance	C _{iss}	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		267		pF
Output Capacitance	C _{oss}			31.5		
Reverse Transfer Capacitance	C _{RSS}			2.5		
Total Gate Charge	Q _G	V _{GS} = 0 to 10V, V _{DS} = 400V, I _D = 3A		11.9		nC
Gate to Source Charge	Q _{GS}			3.7		
Gate to Drain Charge	Q _{GD}			4.5		
Turn-on Delay Time	T _{D(ON)}	V _{DS} = 250V, I _D = 3A, R _G = 25Ω		6		ns
Rise Time	T _r			14		
Turn-off Delay Time	T _{D(OFF)}			15		
Fall Time	T _f			10		
Drain to Source Diode Forward Voltage	V _{SD}	V _{GS} = 0V, I _S = 3A			1.4	V
Body Diode Reverse Recovery Time	T _{rr}	IF = 3A, di/dt = 100A/us VR=300V		75		ns
Body Diode Reverse Recovery Charge	Q _{rr}			140		μC

➤ Typical Performance Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

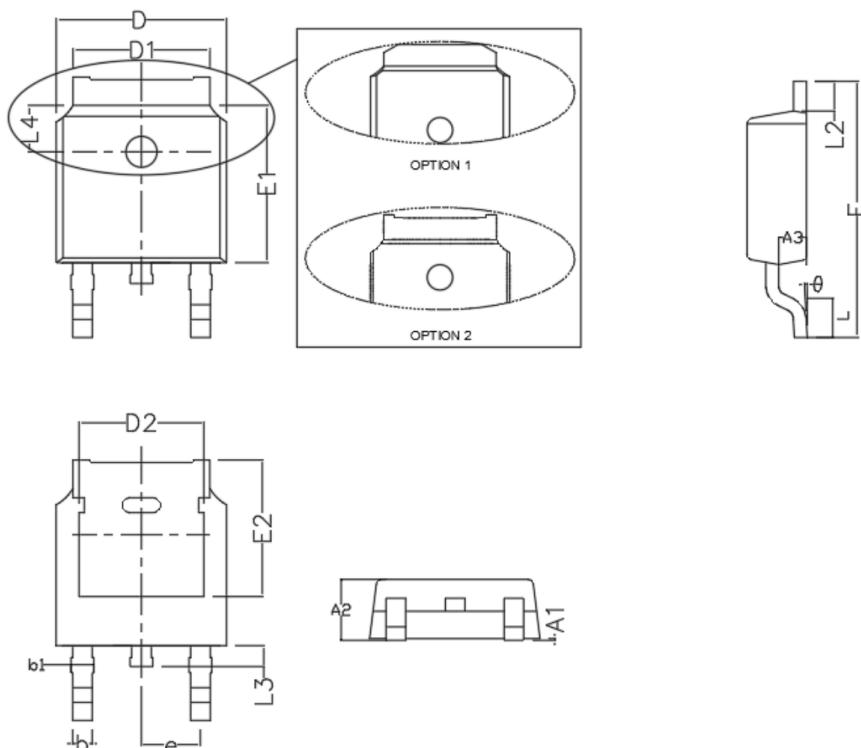


➤ Typical Performance Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)



➤ Package Information

TO252



Symbol	MILL IMETER			Symbol	MILL IMETER		
	Min	Nom	Max		Min	Nom	Max
A1	0.000	/	0.200	E1	5.900	6.100	6.300
A2	2.100	2.300	2.400	E2	5.100	5.450	5.600
A3	0.900	1.040	1.170	e	2.286TYP		
b	0.635	0.762	0.910	L	1.270	1.500	2.032
b1	0.680	0.840	1.145	L2	0.900	1.100	1.270
D	6.350	6.600	6.800	L3	0.600	0.800	1.000
D1	4.950	5.330	5.500	L4	1.600	1.800	2.000
D2	4.315	4.830	5.230	θ	0°	/	10°
E	9.395	10.100	10.500				



DISCLAIMER

SSCSEMI RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. SSCSEMI DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENCE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

THE GRAPHS PROVIDED IN THIS DOCUMENT ARE STATISTICAL SUMMARIES BASED ON A LIMITED NUMBER OF SAMPLES AND ARE PROVIDED FOR INFORMATIONAL PURPOSE ONLY. THE PERFORMANCE CHARACTERISTICS LISTED IN THEM ARE NOT TESTED OR GUARANTEED. IN SOME GRAPHS, THE DATA PRESENTED MAY BE OUTSIDE THE SPECIFIED OPERATING RANGE (E.G. OUTSIDE SPECIFIED POWER SUPPLY RANGE) AND THEREFORE OUTSIDE THE WARRANTED RANGE.

OUR PRODUCT SPECIFICATIONS ARE ONLY VALID IF OBTAINED THROUGH THE COMPANY'S OFFICIAL WEBSITE, CRM SYSTEM, OR OUR SALES PERSONNEL CHANNELS. IF CHANGES OR SPECIAL VERSIONS ARE INVOLVED, THEY MUST BE STAMPED WITH A QUALITY SEAL AND MARKED WITH A SPECIAL VERSION NUMBER TO BE VALID.